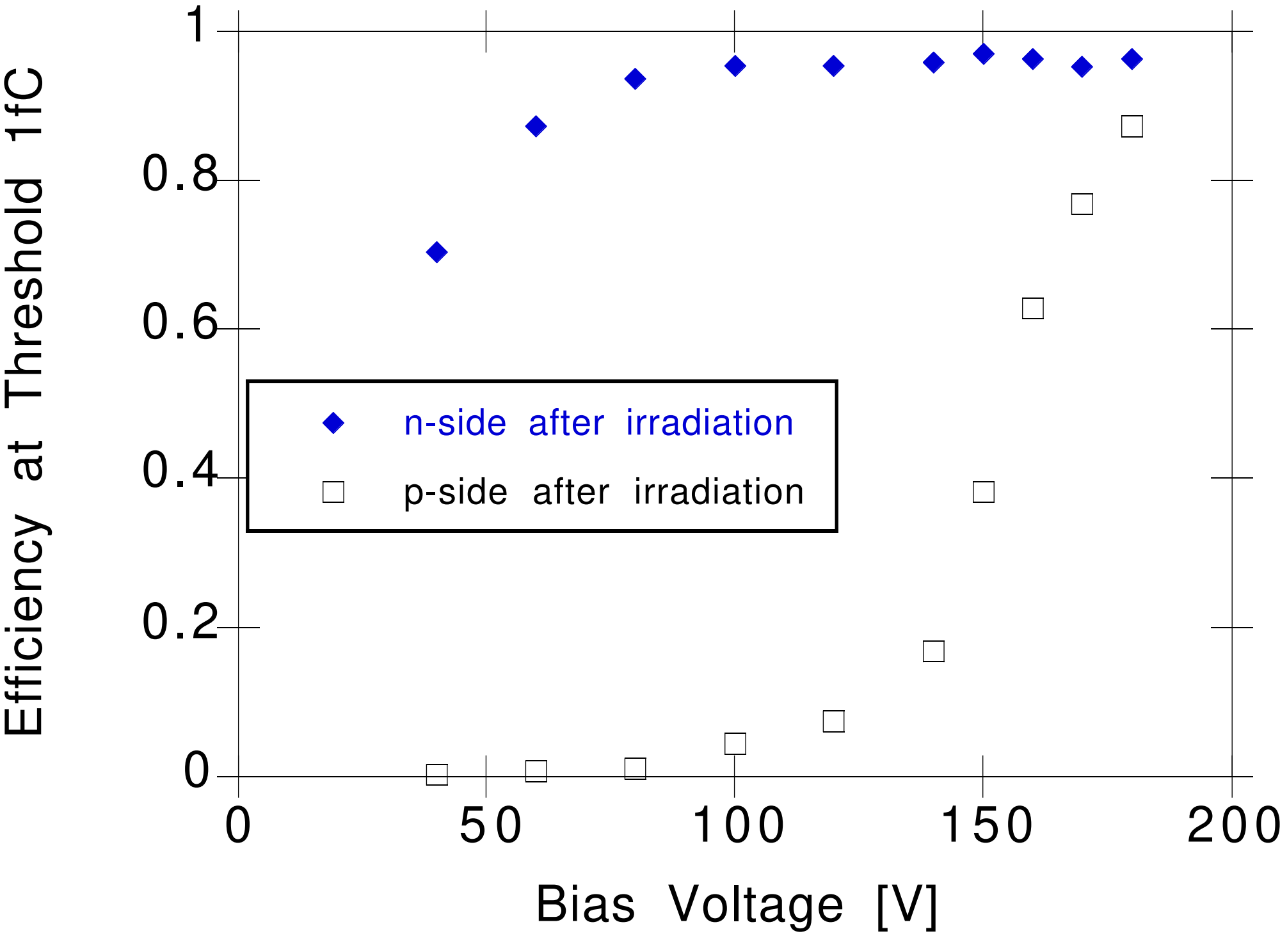
Efficiency at Threshold 1fC
1
0.8
0.6
0.4
0.2
0
0
50
100
150
200
Bias Voltage [V]
n-side after irradiation
p-side after irradiation